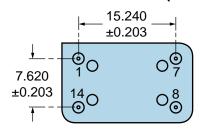


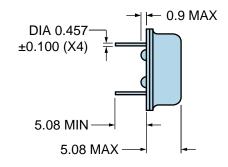
| ELECTRICAL SPECIFICAT           | TIONS CONTRACTOR OF THE PROPERTY OF THE PROPER |
|---------------------------------|--|
| Nominal Frequency               | 24.704MHz  |
| Frequency Tolerance/Stability   | ±25ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration)   |
| Aging at 25°C                   | ±5ppm/year Maximum   |
| Operating Temperature Range     | 0°C to +70°C   |
| Supply Voltage                  | 5.0Vdc ±5%   |
| Input Current                   | 40mA Maximum   |
| Output Voltage Logic High (Voh) | 2.4Vdc Minimum with TTL Load, Vdd-0.5Vdc with HCMOS Load   |
| Output Voltage Logic Low (Vol)  | 0.4Vdc Maximum with TTL Load, 0.5Vdc Maximum with HCMOS Load   |
| Rise/Fall Time                  | 5nSec Maximum (0.4Vdc to 2.4Vdc w/TTL Load, 20% to 80% of waveform w/HCMOS Load)   |
| Duty Cycle                      | 50 ±5(%) (Measured at 1.4Vdc with TTL Load or with HCMOS Load)   |
| Load Drive Capability           | 10TTL Load or 15pF HCMOS Load Maximum  |
| Output Logic Type               | CMOS   |
| Control Voltage                 | 2.5Vdc ±2.0Vdc   |
| Frequency Deviation             | ±50ppm Minimum   |
| Linearity                       | 20% Maximum  |
| Transfer Function               | Positive Transfer Characteristic   |
| Absolute Clock Jitter           | ±100pSec Maximum   |
| One Sigma Clock Period Jitter   | ±25pSec Maximum  |
| Start Up Time                   | 10mSec Maximum   |
| Storage Temperature Range       | -55°C to +125°C  |

| ENVIRONMENTAL & MECHANICAL SPECIFICATIONS |                                       |  |
|---|---------------------------------------|--|
| Fine Leak Test                            | MIL-STD-883, Method 1014, Condition A |  |
| Gross Leak Test                           | MIL-STD-883, Method 1014, Condition C |  |
| Lead Integrity                            | MIL-STD-883, Method 2004              |  |
| Mechanical Shock                          | MIL-STD-202, Method 213, Condition C  |  |
| Resistance to Soldering Heat              | MIL-STD-202, Method 210               |  |
| Resistance to Solvents                    | MIL-STD-202, Method 215               |  |
| Solderability                             | MIL-STD-883, Method 2003              |  |
| Temperature Cycling                       | MIL-STD-883, Method 1010              |  |
| Vibration                                 | MIL-STD-883, Method 2007, Condition A |  |



### **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



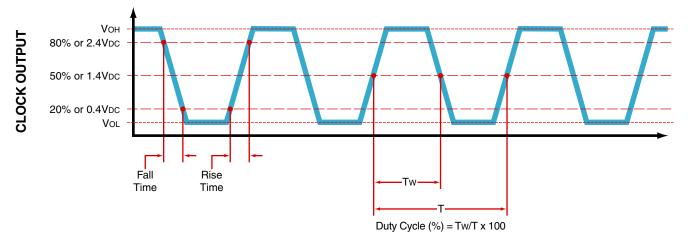


| PIN | CONNECTION         |
|-----|--------------------|
| 1   | Control Voltage    |
| 7   | Ground/Case Ground |
| 8   | Output             |
| 14  | Supply Voltage     |

| LINE | MARKING   |
|------|---|
| 1    | ECLIPTEK  |
| 2    | EC31<br>EC31=Product Series   |
| 3    | 24.704M   |
| 4    | XXYZZ XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year |

# 13.2 MAX ORIENTATION 20.8 MAX

#### **OUTPUT WAVEFORM**





### **Test Circuit for TTL Output**

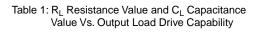
Voltage

Meter

Power

Supply

| Output Load<br>Drive Capability | R <sub>L</sub> Value<br>(Ohms) | C <sub>L</sub> Value<br>(pF) |
|---------------------------------|--------------------------------|------------------------------|
| 10TTL                           | 390                            | 15                           |
| 5TTL                            | 780                            | 15                           |
| 2TTL                            | 1100                           | 6                            |
| 10LSTTL                         | 2000                           | 15                           |
| 1TTL                            | 2200                           | 3                            |



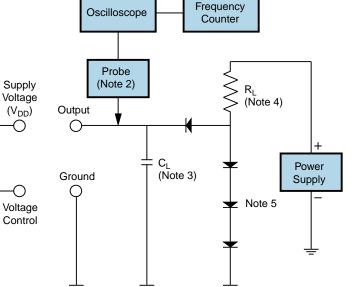
Current Meter

0.01µF

(Note 1)

Voltage

Meter



Note 1: An external  $0.1\mu\text{F}$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu\text{F}$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

0.1µF

(Note 1)

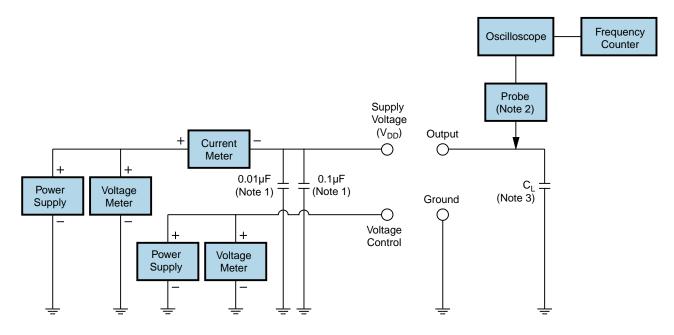
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value  $C_{\mathsf{L}}$  includes sum of all probe and fixture capacitance.
- Note 4: Resistance value R<sub>L</sub> is shown in Table 1. See applicable specification sheet for 'Load Drive Capability'.
- Note 5: All diodes are MMBD7000, MMBD914, or equivalent.

Power

Supply



#### **Test Circuit for CMOS Output**



Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V<sub>DD</sub> pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



## **Recommended Solder Reflow Methods**



### **High Temperature Solder Bath (Wave Solder)**

|   | ,  |  |
|---|--|--|
| T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate) | 3°C/second Maximum   |  |
| Preheat   |  |  |
| - Temperature Minimum (Ts MIN)                      | 150°C  |  |
| - Temperature Typical (T <sub>s</sub> TYP)          | 175°C  |  |
| - Temperature Maximum (T <sub>s</sub> MAX)          | 200°C  |  |
| - Time (t <sub>s</sub> MIN)                         | 60 - 180 Seconds   |  |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 3°C/second Maximum   |  |
| Time Maintained Above:                              |  |  |
| - Temperature (T <sub>L</sub> )                     | 217°C  |  |
| - Time (t∟)   | 60 - 150 Seconds   |  |
| Peak Temperature (T <sub>P</sub> )                  | 260°C Maximum for 10 Seconds Maximum   |  |
| Target Peak Temperature (T <sub>P</sub> Target)     | 250°C +0/-5°C  |  |
| Time within 5°C of actual peak (tp)                 | 20 - 40 seconds  |  |
| Ramp-down Rate                                      | 6°C/second Maximum   |  |
| Time 25°C to Peak Temperature (t)                   | 8 minutes Maximum  |  |
| Moisture Sensitivity Level                          | Level 1  |  |
| Additional Notes                                    | Temperatures shown are applied to back of PCB board and device leads only. Do not use this method for product with the Gull Wing option. |  |
|   |  |  |



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 185°C

| •   |  |  |
|---|--|--|
| T <sub>s</sub> MAX to T <sub>L</sub> (Ramp-up Rate) | 5°C/second Maximum   |  |
| Preheat   |  |  |
| - Temperature Minimum (T <sub>s</sub> MIN)          | N/A  |  |
| - Temperature Typical (T <sub>s</sub> TYP)          | 150°C  |  |
| - Temperature Maximum (T <sub>s</sub> MAX)          | N/A  |  |
| - Time (t <sub>s</sub> MIN)                         | 60 - 120 Seconds   |  |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 5°C/second Maximum   |  |
| Time Maintained Above:                              |  |  |
| - Temperature (T <sub>L</sub> )                     | 150°C  |  |
| - Time (t∟)   | 200 Seconds Maximum  |  |
| Peak Temperature (T <sub>P</sub> )                  | 185°C Maximum  |  |
| Target Peak Temperature (T <sub>P</sub> Target)     | 185°C Maximum 2 Times  |  |
| Time within 5°C of actual peak (tp)                 | 10 seconds Maximum 2 Times   |  |
| Ramp-down Rate                                      | 5°C/second Maximum   |  |
| Time 25°C to Peak Temperature (t)                   | N/A  |  |
| Moisture Sensitivity Level                          | Level 1  |  |
| Additional Notes                                    | Temperatures shown are applied to body of device. Use this method for product with the Gull Wing option. |  |
|   |  |  |



## **Recommended Solder Reflow Methods**



#### **Low Temperature Solder Bath (Wave Solder)**

|   | ,  |
|---|--|
| T <sub>s</sub> MAX to T <sub>∟</sub> (Ramp-up Rate) | 5°C/second Maximum   |
| Preheat   |  |
| - Temperature Minimum (T <sub>S</sub> MIN)          | N/A  |
| - Temperature Typical (T <sub>s</sub> TYP)          | 150°C  |
| - Temperature Maximum (T <sub>s</sub> MAX)          | N/A  |
| - Time (t <sub>s</sub> MIN)                         | 30 - 60 Seconds  |
| Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )    | 5°C/second Maximum   |
| Time Maintained Above:                              |  |
| - Temperature (T <sub>L</sub> )                     | 150°C  |
| - Time (t∟)   | 200 Seconds Maximum  |
| Peak Temperature (T <sub>P</sub> )                  | 245°C Maximum  |
| Target Peak Temperature (T <sub>P</sub> Target)     | 245°C Maximum 1 Time / 235°C Maximum 2 Times   |
| Time within 5°C of actual peak (t <sub>p</sub> )    | 5 seconds Maximum 1 Time / 15 seconds Maximum 2 Times  |
| Ramp-down Rate                                      | 5°C/second Maximum   |
| Time 25°C to Peak Temperature (t)                   | N/A  |
| Moisture Sensitivity Level                          | Level 1  |
| Additional Notes                                    | Temperatures shown are applied to back of PCB board and device leads only. Do not use this method for product with the Gull Wing option. |
|   |  |

#### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum. (Temperatures listed are applied to device leads only. This method can be utilized with both Gull Wing and Non-Gull Wing devices.)

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum. (Temperatures listed are applied to device leads only. This method can be utilized with both Gull Wing and Non-Gull Wing devices.)